

Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

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	Data	Sheet

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Part Number / Ordering Information ^{1/}				
SPD _				
	TX = TX Level TXV = TXV Level, S = S-Level — = Not Screened Package = Axial Leaded SMS = Surface Mount Square Tab			
	Voltage / Family 0801 = 80V			

0901 = 90V1001 = 100V

SPD0801 – SPD1001SMS and SPD0801SMS - SPD1001SMS

1 AMP 80-100 VOLTS SCHOTTKY RECTIFIER

FEATURES:

- Extremely Low Forward Voltage Drop
- High Surge Capability
- PIV to 100 Volts
- Low Reverse Leakage Current
- High Voltage Replacement for 1N5817-1N5819 Series
- Surface Mount Versions Available
- TX, TXV, and Space Level Screening Available^{2/}

MAXIMUM RATINGS			Symbol	Value	Units
Peak Repetitive Reverse Voltage Blocking Voltage	and DC	SPD0801SMS SPD0901SMS SPD1001SMS	$egin{array}{c} \mathbf{V_{RRM}} \ \mathbf{V_{RWM}} \ \mathbf{V_{R}} \end{array}$	80 90 100	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A =25 °C)		I_0	1	Amps	
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on I _O , allow junction to reach equilibrium between pulses, T _A =25 °C)		I_{FSM}	40	Amps	
Operating and Storage Temperature		T _{OP} & Tstg	-55 to +125	$^{\circ}\mathbf{C}$	
Maximum Thermal Resistance	Jun	uction to Lead, L=3/8" Junction to End	$R_{ heta m JL} \ R_{ heta m JE}$	46 20	°C/W

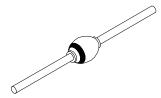
NOTES:

 $\underline{\mathbf{1}}/$ For ordering information, price, and availability, contact factory.

2/ Screening based on MIL-PRF-19500. Screening flows available on request.

Axial Leaded

Surface Mount Square Tab (SMS)





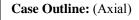


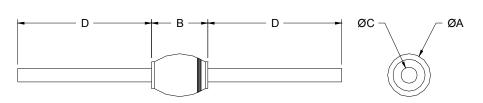
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$SPD0801-SPD1001SMS\\ and\\ SPD0801SMS-SPD1001SMS$

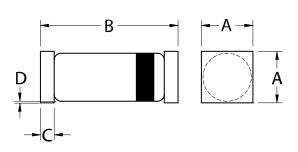
ELECTRICAL CHARACTERISTICS	Symbol	Max	Unit
Instantaneous Forward Voltage Drop $(I_F = 0.5A_{DC}, T_A = 25^{\circ}C, 300 \mu s Pulse)$ $(I_F = 1A_{DC}, T_A = 25^{\circ}C, 300 \mu s Pulse)$	$\mathbf{V_F}$	0.75 0.95	Vdc
Instantaneous Forward Voltage Drop (I _F = 1A _{DC} , T _A = -55 °C, 300 μs Pulse)	$\mathbf{V_F}$	1.0	Vdc
Reverse Leakage Current (Rated V _R , T _A = 25 °C, 300 μs minimum Pulse)	I_R	200	μА
Reverse Leakage Current (Rated V _R , T _A = 100 °C, 300 μs minimum Pulse)	I_R	10	mA
Junction Capacitance (V _R = 10 V _{DC} , T _A = 25 °C, f = 1 MHz)	C _J	30	pF





DIMENSIONS			
DIM	MIN	MAX	
A	.080"	.107"	
В	.160"	.205"	
C	.028"	.032"	
D	1.00"		

Case Outline: (SMS)



DIMENSIONS			
DIM	MIN	MAX	
A	.125"	.135"	
В	.180"	.235"	
С	.022"	.028"	
D	.090"	.110"	